

# ANGI064072-P52

# **C-band matched GaN Device**

#### Features:

Frequency:  $6.4 \sim 7.2$  GHz Saturated Output Power:  $P_{sat} \ge 52$  dBm PowerGain: Gain  $\ge 9$  dB Add-Efficiency: PAE  $\ge 40\%$ Port Matching:  $Z_{in}/Z_{out} = 50\Omega$ 

#### **Description**:

ANGI064072-P52 is an internal matching GaN device, which adopts advanced co-planar internal matching MCM and thin film circuit technology. The typical working frequency range is 6.4~7.2GHz. This device can be used in different RF/Microwave system and subsystem.

The high output power level, high efficiency and wide operating temperature range can make application very flexible.

# Maximun Ratings (TC=25°C, Not recommended working under this condition):

	Symbol	Value	Unit
Voltage between source and drain	Vds	40	V
Voltage between gate and source	V <sub>GS</sub>	-5	V
Storage Temperature Range	Tstg	-65 to +175	°C
Drain and Source Channel Temperature	Tch	175	°C

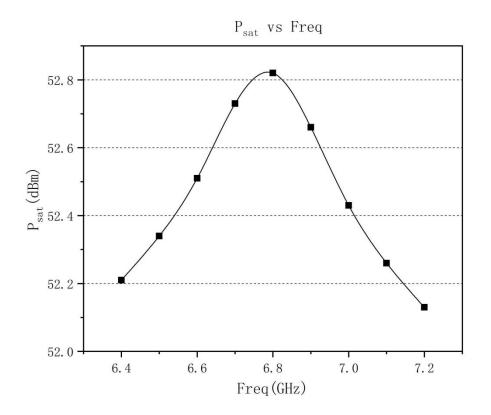
1



# **Electrical Characteristics:**

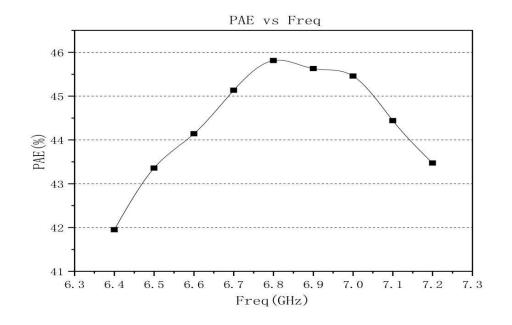
			Value			
	Symbol	Test condition	Min	Тур	Max	Unit
Drain Current	ldsr	Vds=28V PW. T=1ms, Duty=10% Pin: 43dBm Freq: 6.4~7.2GHz	-	12.5	-	А
Saturated Output Power	Psat		52	-	_	dBm
Gain	Gp		9	-	-	dB
Add-Efficiency	PAE		40	-	-	%
Gain Flatness	ΔG		-0.8	_	+0.8	dB

# **Typical Curve:**

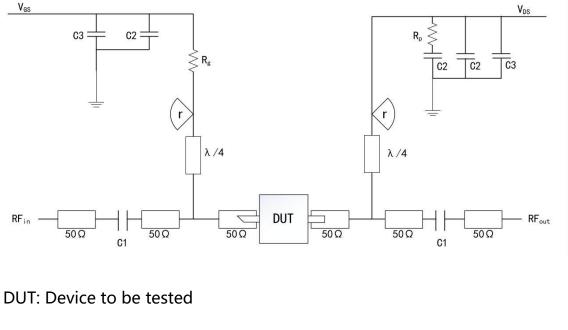


If you need more detailed product information, please contact our marketing personnel or designers. Contact: Peter.Zhang Email: peter.zhang@anserrf.com





## **Application Circuit:**



C1:3pF	R <sub>p</sub> :51Ω
C2:1000pF	R <sub>G</sub> :15Ω
C3:100uF	r(radius)≈4.5mm(Rogers5880, 20mil)

If you need more detailed product information, please contact our marketing personnel or designers. Contact: Peter.Zhang Email: peter.zhang@anserrf.com

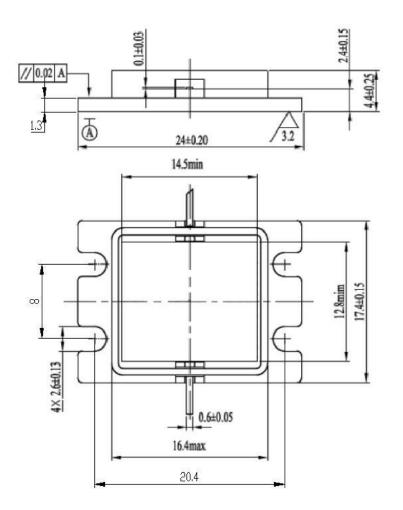
3



#### **ESD Level:**



#### **Outline:**



#### **Precautions for use:**

- Pay attention to drying transportation and storage.
- Pay attention to anti-static during chip use and assembly, and wear grounding anti-static bracelet.
- When powering up, first apply grid power then add leakage.

4